NSN 5961-01-104-0179

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-104-0179 **Inclosure Material:** Plastic **Overall Length:** Between 0.280 inches and 0.320 inches **Overall Width:** Between 0.360 inches and 0.410 inches **Mounting Facility Quantity: Internal Configuration:** Field effect **Electrode Internally-electrically Connected To Case:** Drain **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 drain to gate voltage and 60.0 drain to source voltage **Current Rating Per Characteristic:** 2.00 amperes drain current and 2.00 milliamperes gate current **Power Rating Per Characteristic:** 2.1 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius case **Terminal Type And Quantity:** 3 tab w/wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No